



DMPH4016SPSWQ

40V 175°C P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) max	I⊳ Tc = +25°C
-40V	10mΩ @ V _{GS} = -10V	-90.7 A
-40 V	14mΩ @ V _{GS} = -4.5V	-79.8 A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

PowerDI5060-8/SWP (Type UX)

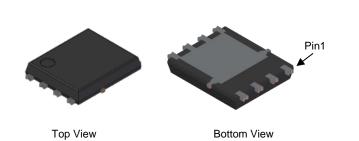
- **DC-DC** converters
- Power-management functions
- Analog switches

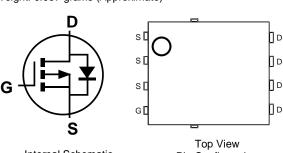
Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switch (UIS) Test in Production •
- Low On-Resistance •
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspections
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMPH4016SPSWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 gualified, PPAP capable, and manufactured in IATF 16949 certified facilities. https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)





Internal Schematic

Pin Configuration

Ordering Information (Note 4)

Part Number	Deskare	Packing		
Part Number	Package	Qty.	Carrier	
DMPH4016SPSWQ-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel	

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. Notes: 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



 $\supset ! ! = Manufacturer's Marking$ PH4016SW = Product Type Marking Code YYWW = Date Code Marking \overline{YY} = Year (ex: 23 = 2023) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	-40	V		
Gate-Source Voltage	Vgss	±20	V		
Continuous Drain Current (Note 6) V_{GS} = -10V	Steady State	Tc = +25°C Tc = +100°C	ID	-90.7 -64.3	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%		Ідм	-363	А	
Maximum Body Diode Continuous Current (Note 6)		Is	-90	А	
Pulsed Source Current (10µs Pulse, Duty Cycle = 1	lsм	-363	А		
Avalanche Current L = 1mH			las	-28.9	А
Avalanche Energy L = 1mH			E _{AS}	418.6	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T _A = +25°C	PD	4.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	32	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	143	W
Thermal Resistance, Junction to Case (Note 6)	Rejc	1.05	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C	

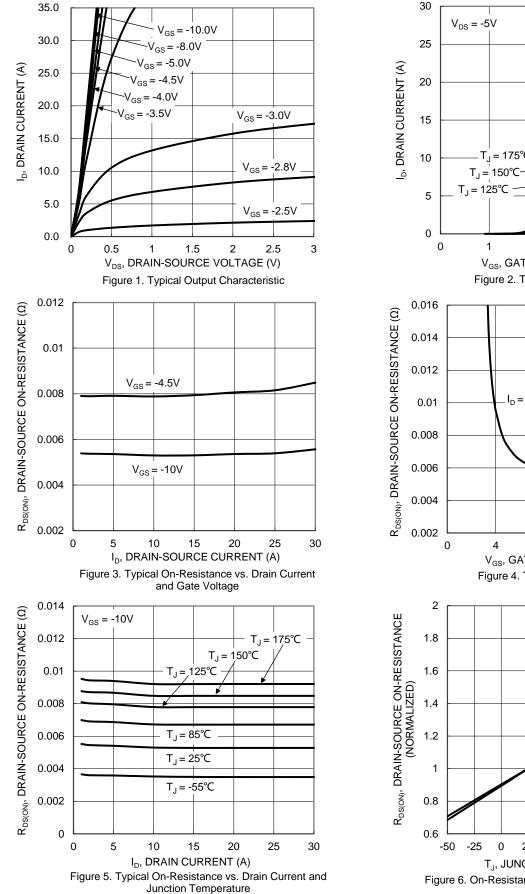
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

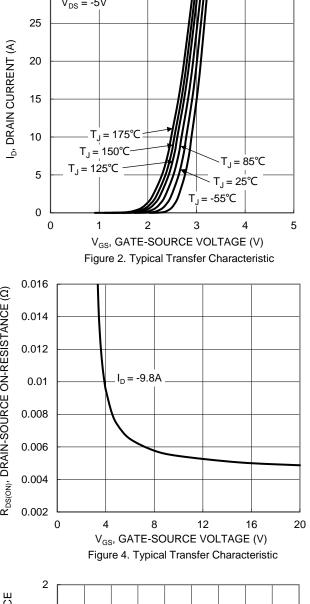
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	-1	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	-1.5	_	-2.5	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Deserve	_	5.4	10	mΩ	V _{GS} = -10V, I _D = -9.8A	
Static Drain-Source On-Resistance	RDS(ON)		8.0	14	1112	V _{GS} = -4.5V, I _D = -9.8A	
Diode Forward Voltage	Vsd	_	-0.67	-1	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)	•						
Input Capacitance	Ciss	_	5697	_		V _{DS} = -20V, V _{GS} = 0V f = 1MHz	
Output Capacitance	Coss	_	534	_	pF		
Reverse Transfer Capacitance	Crss		408	_			
Gate Resistance	Rg	_	7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	53	_		V 00V L 0.04	
Total Gate Charge (V _{GS} = -10V)	Qg		112	—	nC		
Gate-Source Charge	Q _{gs}	_	20	_	nc	$V_{DS} = -20V, I_{D} = -9.8A$	
Gate-Drain Charge	Q _{gd}		18	—			
Turn-On Delay Time	tD(ON)	_	11.5	_			
Turn-On Rise Time	tR		41	_		$V_{GS} = -10V, V_{DD} = -20V,$	
Turn-Off Delay Time	tD(OFF)		146	_	ns	$R_G = 2\Omega$, $I_D = -9.8A$	
Turn-Off Fall Time	tF		165	_			
Reverse Recovery Time	trr		27	—	ns	IF = -9.8A, di/dt = -100A/µs	
Reverse Recovery Charge	Q _{RR}		22	_	nC	I _F = -9.8A, di/dt = -100A/µs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



DMPH4016SPSWQ





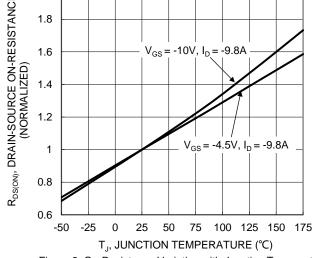
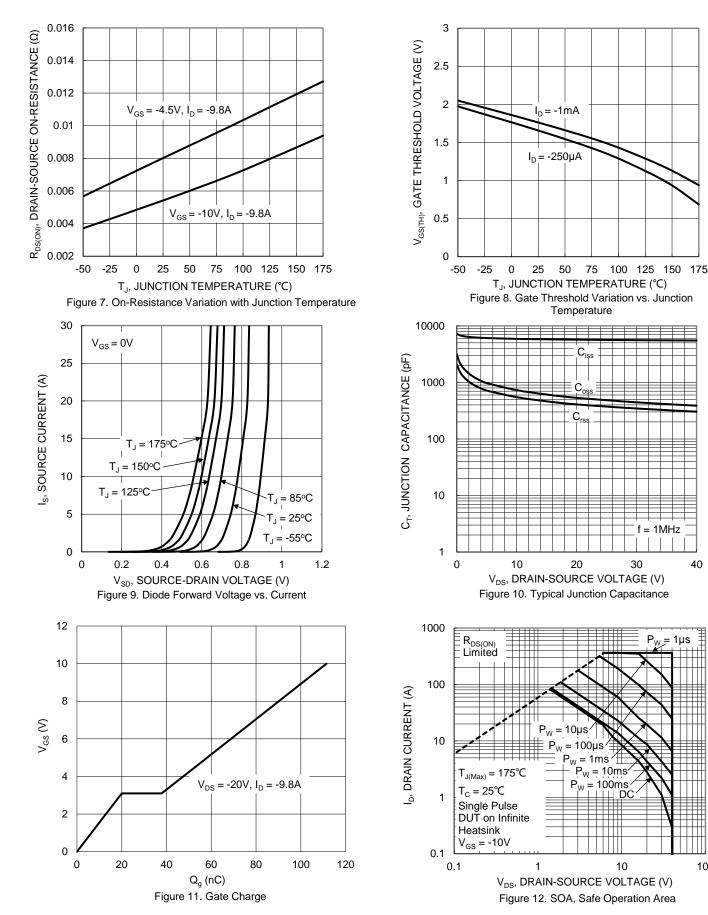


Figure 6. On-Resistance Variation with Junction Temperature

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DMPH4016SPSWQ



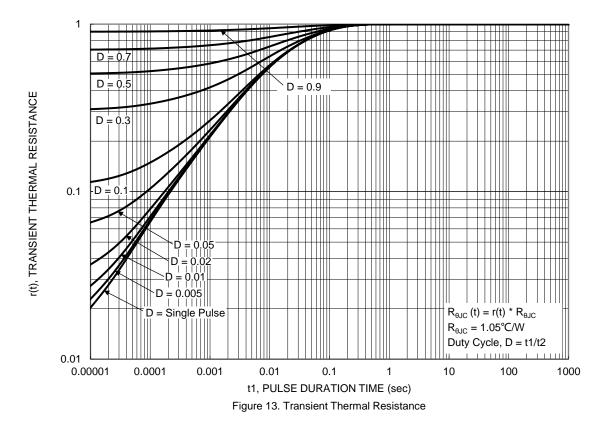
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1µs

100



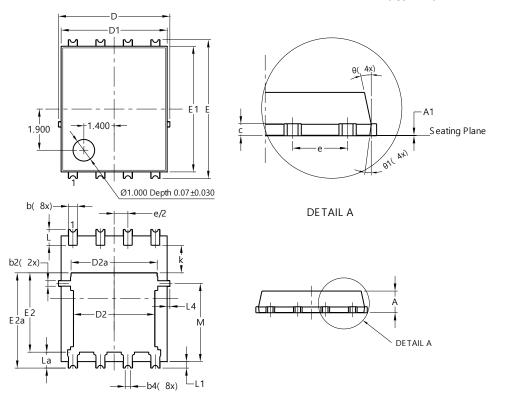






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

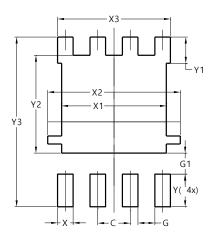


PowerDI5060-8/SWP (Type UX)					
Dim	Min	Тур			
Α	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	().25REF			
c	0.230	0.330	0.277		
D		.15 BS(2		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
ш	-	.40 BS0	-		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195 4.595 4.395				
е	1	.27BSC)		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a	0.050REF				
L4	0.025	0.225	0.125		
М	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	Dimensi	ions in	mm		

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)		
Dimensions			
С	1.270		
G	0.660		
G1	0.820		
Х	0.610 4.100 5.190		
X1			
X2			
X3	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		

PowerDI5060-8/SWP (Type UX)



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